

Description

GM9601 is monolithic integrated circuit of a general-purpose driver designed to control brightness of LED lamps in wide limits.

The circuit is highly efficient for small sizes of lighting-intended LED clusters.

GM9601 is available in Power SO 8 package.

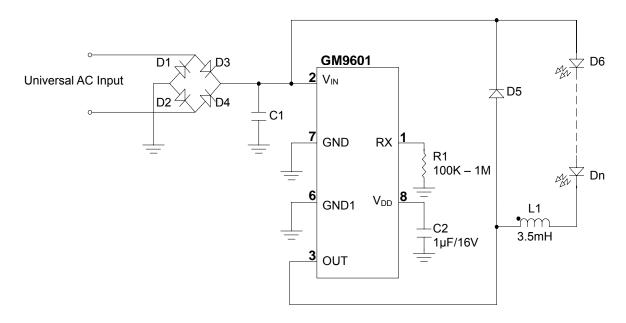
Features

- ♦ Internal built MOSFET
- EX pin current enabling to control LED peak current, turn of and off
- Constant specified load current, which is maintained with the wide range of input voltage from 50V to 500V
- Over temperature protection (OPT)with 30°C hystereis

Applications

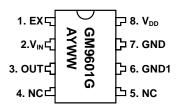
- Flat panel display backlighting
- General purpose constant current source

Typical Application Circuit





Marking Information and Pin Configurations (Top View)



DIP-8 package (Top View)

G: Green Product

A: Assembly / Test site code

Y: Year WW: Week

Pin Descriptions

Pin#	Function	Description
1	EX	Output current, output power transistor turn ON/OFF control input
2	V_{IN}	High voltage supply input
3	OUT	Output power transistor drain
4	-	Not connected
5	-	Not connected
6	GND1	Output power transitor sourse
7	GND	Ontrol circuit common
9	VDD	VDD Voltage

Ordering Information

Ordering Number	Package	Shipping
GM9601D8TG	DIP8	60 Units / Tube

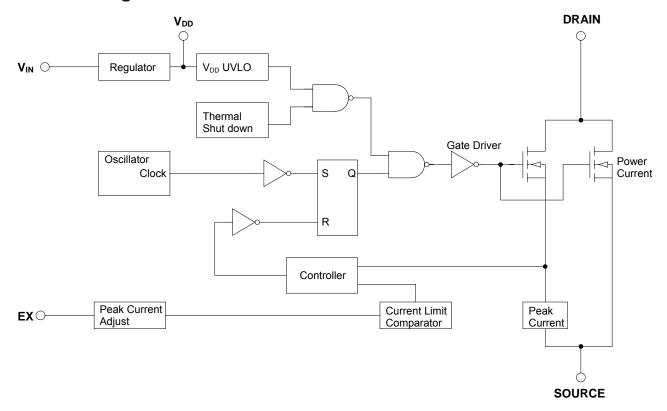


Absolute Maximum Ratings

PARAMETER	RATINGS		
VIN to GND	700V		
Operating Temperature Range	- 40°C to + 85°C		
Junction Temperature	+125°C		
Storage Temperature	- 65°C to + 150°C		

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

Block Diagram



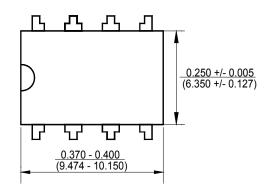


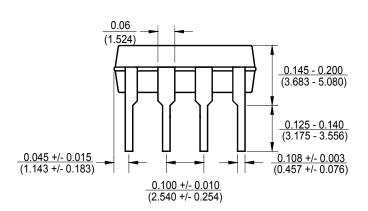
Electrical Characteristics (T_A = 25°C, unless otherwise specified)

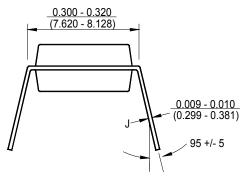
Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit
Input voltage range	V _{IN}		50		700	V
Current consumption in OFF state	I _{IN_OFF}	V _{IN} = 50V			0.6	mA
Power supply voltage range	V_{DD}	V _{IN} = 10 to 700V, I _{DD} = 0	7.0		8.0	V
Input current in ON state	I _{IN_ON}	V _{IN} = 10 to 100V			1.0	mA
Circuit turn-on voltage	UVLO	V _{IN} increasing	6.45		6.95	V
Power supply voltage hysteresis	ΔUVLO	V _{IN} falling	300		700	mV
EX pin turn off voltage	$V_{\text{EX(hi)}}$		V _{DD} - 1.3		V_{DD}	V
R1 for I _{OUT} = 0.1 x I _{MAX} (Note 1)	R _{EXP1}	V _{IN} = 50V	700		900	kΩ
R1 for I _{OUT} = I _{MAX} (Note 1)	R _{EX}	V _{IN} = 50V	200		300	kΩ
Output peak current	I _{MAX}	V _{IN} = 50V	0.6	0.7	0.8	Α
Static drain-source ON state resistance	R _{DSON}	V _{IN} = 50V, I _{OUT} = 0.6A		6		Ω
Oscillator frequency	f _{OSC}		35.2	44	52.8	kHz
Blanking interval	T _{blank}	V _{IN} = 50V	150		280	ns
Peak current turn on delay	t _D				300	ns
Output rise time	t _r				200	ns
Output fall time	t _f				50	ns
Thermal shutdown junction temperature	TJ			150		°C
Thermal shutdown hysteresis	ΔT _J			30		°C



Package Outline Dimensions - DIP 8









Ordering Number

9601 **D8**

APM Gamma Micro Circuit Type

Package Type PS8:ESOP 8

Shipping Type

R: Taping & Reel

T: Tube

Blank: Pb-free

G:Green

Note:

Pb-free products:

- RoHS compliant and compatible with the current require-ments of IPC/JEDEC J-STD-020.
- Suitable for use in Pb-free soldering processes with 100% matte tin (Sn) plating.

Green products:

- ♦ Lead-free (RoHS compliant)
- Halogen free(Br or Cl does not exceed 900ppm by weight in homogeneous material and total of Br and Cl does not exceed 1500ppm by weight)